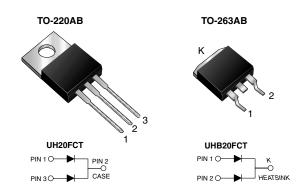




Vishay General Semiconductor

Dual Common-Cathode Ultrafast Recovery Rectifier



PRIMARY CHARACTERISTICS				
I _{F(AV)}	10 A x 2			
V _{RRM}	300 V			
I _{FSM}	180 A			
t _{rr}	25 ns			
V_{F}	0.83 V			
T _J max.	175 °C			

FEATURES

· Oxide planar chip junction



· Ultrafast recovery times



Soft recovery characteristics

RoHS

Low switching losses, high efficiency

· High forward surge capability

- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 s (for TO-220AB package)
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in high frequency power factor correctors, switching mode power supplies, freewheeling diodes and secondary dc-to-dc rectification application.

MECHANICAL DATA

Case: TO-220AB and TO-263AB

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class

1A whisker test **Polarity:** As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER		SYMBOL	UH20FCT UHB20FCT		UNIT	
Maximum repetitive peak reverse voltage		V_{RRM}	300		V	
Maximum average forward rectified current (see Fig.1)	per device per diode	I _{F(AV)}	20 10		Α	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	per diode	I _{FSM}	180		А	
Operating junction and storage temperature range		T _J , T _{STG}	- 55 to + 175		°C	

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CO	NDITIONS	SYMBOL	TYP.	MAX.	UNIT	
Maximum instantaneous forward voltage per diode ⁽¹⁾	I _F = 5.0 A I _F = 5.0 A	$T_J = 25 ^{\circ}\text{C}$ $T_J = 125 ^{\circ}\text{C}$	V_{F}	0.96 0.77	-	· v	
	I _F = 10 A I _F = 10 A	T _J = 25 °C T _J = 125 °C		1.0 0.83	1.2 0.90		

UH20FCT& UHB20FCT

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Maximum reverse current per diode (2)	$V_R = 300 \text{ V}$ $T_J = 25 ^{\circ}\text{C}$ $T_J = 125 ^{\circ}\text{C}$		I _R	0.5 25	5 150	μΑ
Maximum reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A},$ $I_{rr} = 0.25 \text{ A}$		t _{rr}	20	25	ns
Maximum reverse recovery time per diode	$I_F = 1.0 \text{ A}, \text{ dI/dt} = 50 \text{ A/}\mu\text{s}, \\ V_R = 30 \text{ V}, I_{rr} = 0.1 I_{RM}$		t _{rr}	28	35	ns
Typical softness factor (tb/ta)	$I_F = 10 \text{ A}, \text{ dI/dt} = 200 \text{ A/}\mu\text{s},$ $V_R = 200 \text{ V}, T_J = 125 ^{\circ}\text{C}$ per diode		S	0.36	-	-
Typical reverse recovery current			I _{RM}	7.0	-	Α
Typical stored charge			Q_{rr}	160	-	nC
Typical forward recovery time per diode	$I_F = 10 \text{ A}, \text{ dI/dt} = 80 \text{ A/}\mu\text{s},$ $V_{FR} = 1.1 \text{ x} V_{F \text{ max}}.$		t _{fr}	150	-	ns

Notes:

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

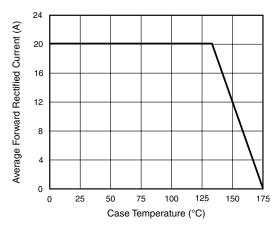
(2) Pulse test: Pulse width \leq 40 ms

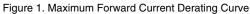
THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL UH20FCT UHB20FCT UNI					
Typical thermal resistance per diode	$R_{ hetaJC}$	2.0	2.0	°C/W		

ORDERING INFORMATION							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	UH20FCT-E3/4W	1.88	4W	50/tube	Tube		
TO-263AB	UHB20FCT-E3/4W	1.38	4W	50/tube	Tube		
TO-263AB	UHB20FCT-E3/8W	1.38	8W	800/reel	Tape and reel		

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)





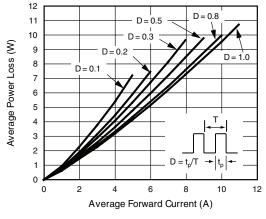


Figure 2. Forward Power Loss Characteristics Per Diode





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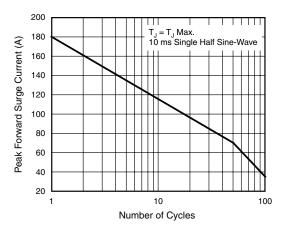


Figure 3. Maximum Non-Repetitive Peak Forward Surge Current Per Diode

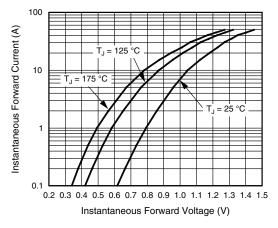


Figure 4. Typical Instantaneous Forward Characteristics Per Diode

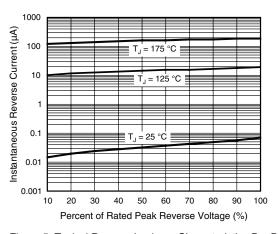


Figure 5. Typical Reverse Leakage Characteristics Per Diode

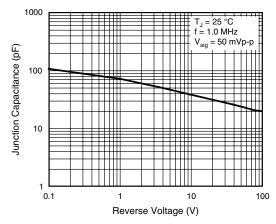


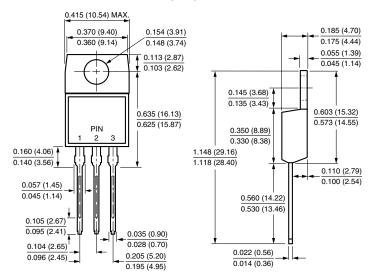
Figure 6. Typical Junction Capacitance Per Diode

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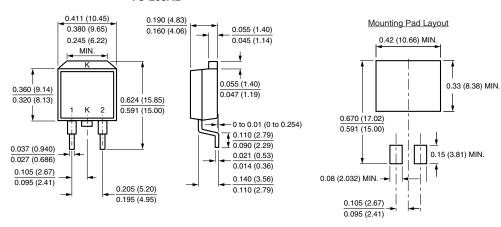


PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-220AB



TO-263AB





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